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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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H5N1506P

Silicon N Channel MOS FET High Speed Power Switching

REJ03G0389-0200

Rev.2.00

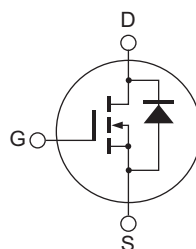
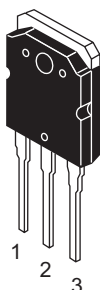
Jul 03, 2006

Features

- Low on-resistance
- Low leakage current
- High speed switching

Outline

RENESAS Package code: PRSS0004ZE-A
(Package name: TO-3P)



1. Gate
2. Drain (Flange)
3. Source

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Drain to Source voltage	V_{DSS}	150	V
Gate to Source voltage	V_{GSS}	± 30	V
Drain current	I_D	98	A
Drain peak current	$I_{D(pulse)}$ ^{Note1}	294	A
Body-Drain diode reverse Drain current	I_{DR}	98	A
Body-Drain diode reverse Drain peak current	$I_{DR(pulse)}$ ^{Note1}	294	A
Avalanche current	I_{AP} ^{Note3}	48	A
Avalanche energy	E_{AR} ^{Note3}	172	mJ
Channel dissipation	P_{ch} ^{Note2}	150	W
Channel to case thermal impedance	θ_{ch-c}	0.833	$^\circ\text{C}/\text{W}$
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: 1. $PW \leq 10 \mu\text{s}$, duty cycle $\leq 1\%$

2. Value at $T_c = 25^\circ\text{C}$

3. $STch = 25^\circ\text{C}$, $T_{ch} \leq 150^\circ\text{C}$

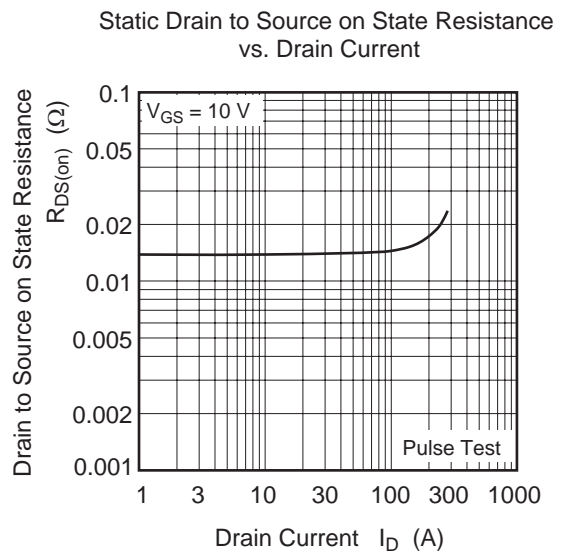
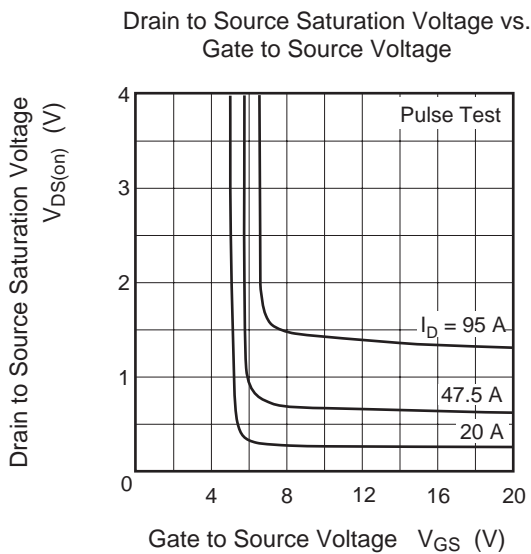
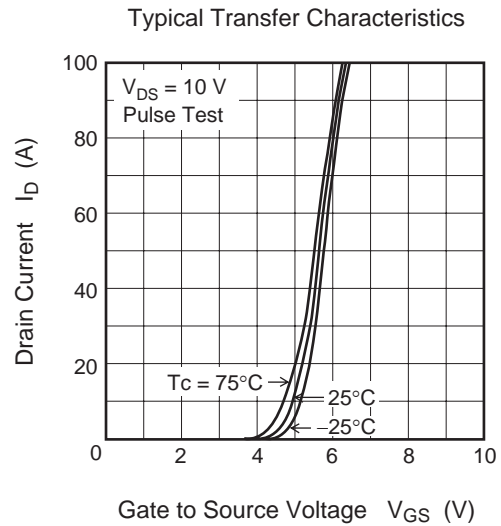
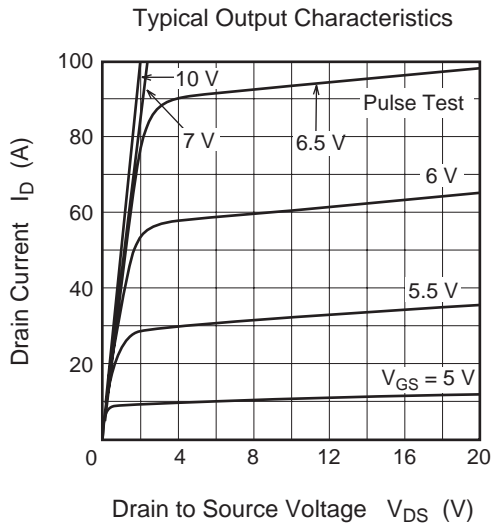
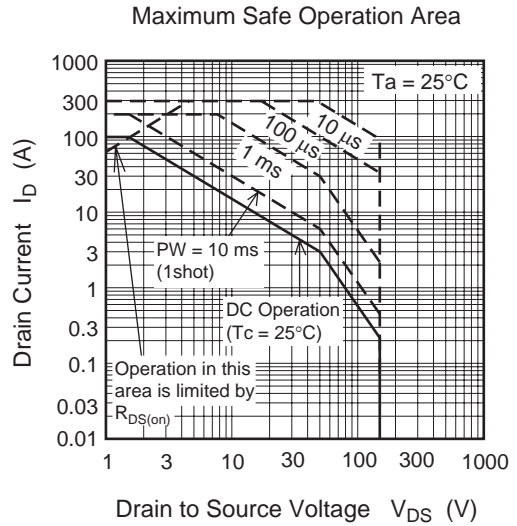
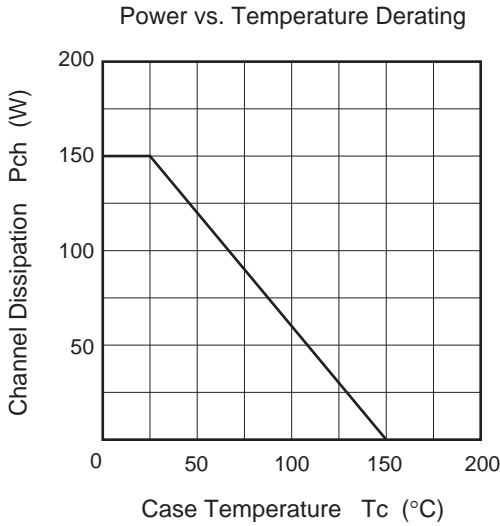
Electrical Characteristics

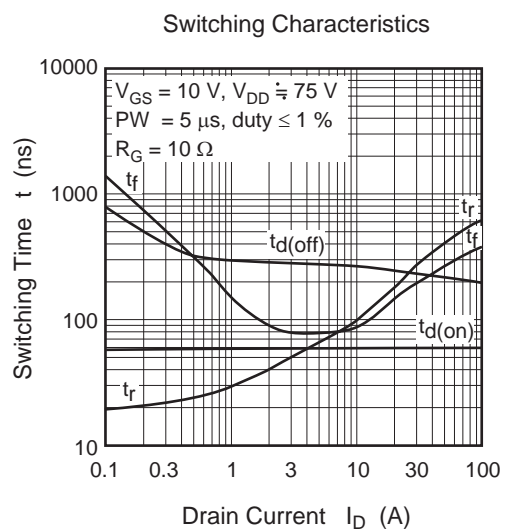
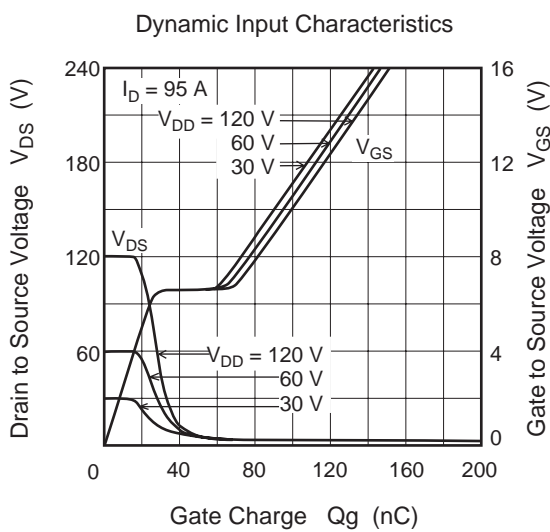
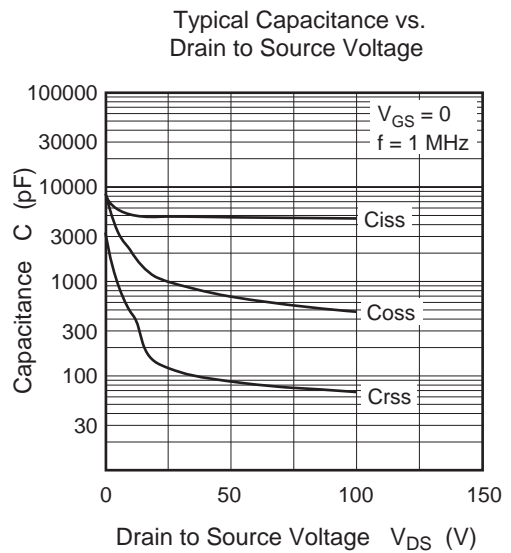
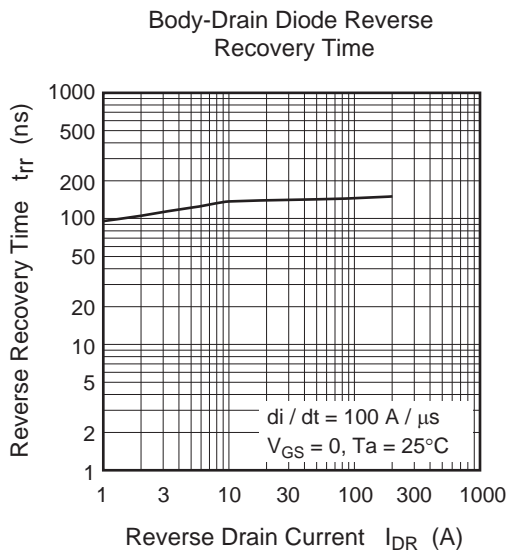
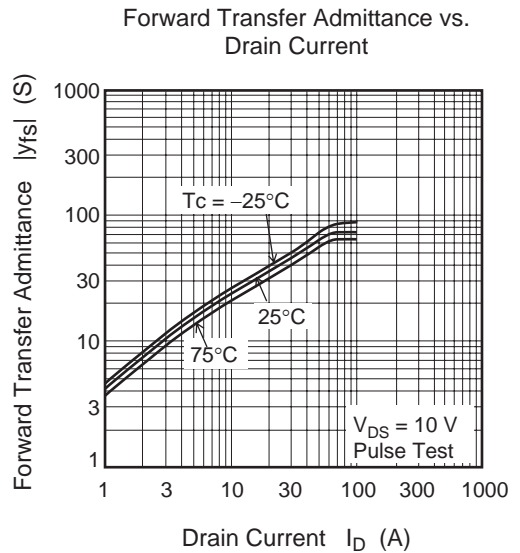
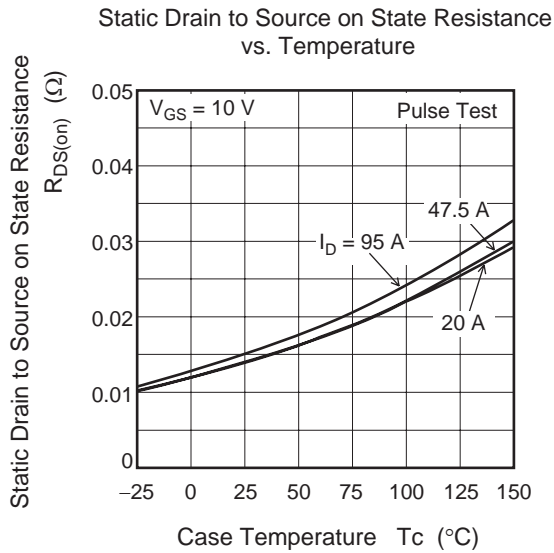
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to Source breakdown voltage	$V_{(BR)DSS}$	150	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Zero Gate voltage Drain current	I_{DSS}	—	—	1	μA	$V_{DS} = 150 \text{ V}$, $V_{GS} = 0$
Gate to Source leak current	I_{GSS}	—	—	± 0.1	μA	$V_{GS} = \pm 30 \text{ V}$, $V_{DS} = 0$
Gate to Source cutoff voltage	$V_{GS(off)}$	3.0	—	4.5	V	$V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$
Forward transfer admittance	$ y_{fs} $	36	60	—	S	$I_D = 47.5 \text{ A}$, $V_{DS} = 10 \text{ V}$ ^{Note4}
Static Drain to Source on state resistance	$R_{DS(on)}$	—	0.014	0.016	Ω	$I_D = 47.5 \text{ A}$, $V_{GS} = 10 \text{ V}$ ^{Note4}
Input capacitance	C_{iss}	—	4900	—	pF	$V_{DS} = 25 \text{ V}$
Output capacitance	C_{oss}	—	1000	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	C_{rss}	—	120	—	pF	$f = 1 \text{ MHz}$
Turn-on delay time	$t_{d(on)}$	—	60	—	ns	$I_D = 47.5 \text{ A}$
Rise time	t_r	—	380	—	ns	$V_{GS} = 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	220	—	ns	$R_L = 1.58 \Omega$
Fall time	t_f	—	250	—	ns	$R_g = 10 \Omega$
Total Gate charge	Q_g	—	100	—	nC	$V_{DD} = 120 \text{ V}$
Gate to Source charge	Q_{gs}	—	24	—	nC	$V_{GS} = 10 \text{ V}$
Gate to Drain charge	Q_{gd}	—	45	—	nC	$I_D = 95 \text{ A}$
Body-Drain diode forward voltage	V_{DF}	—	1.0	1.5	V	$I_F = 95 \text{ A}$, $V_{GS} = 0$ ^{Note4}
Body-Drain diode reverse recovery time	t_{rr}	—	150	—	ns	$I_F = 95 \text{ A}$, $V_{GS} = 0$
Body-Drain diode reverse recovery charge	Q_{rr}	—	1.0	—	μC	$di_F/dt = 100 \text{ A}/\mu\text{s}$

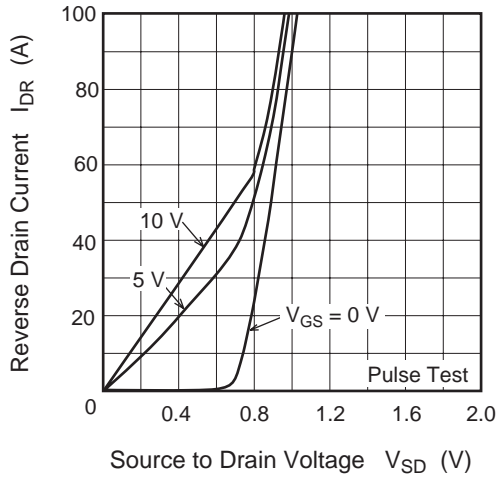
Notes: 4. Pulse test

Main Characteristics

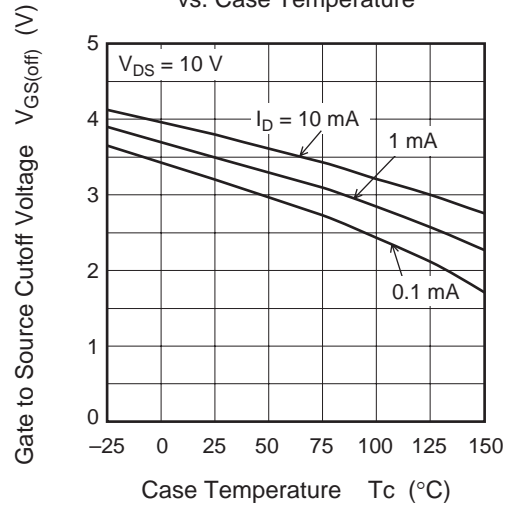




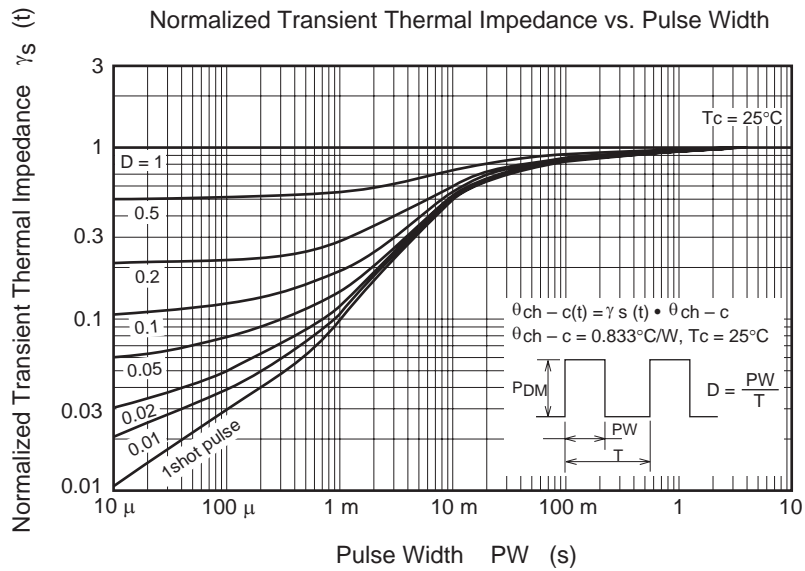
Reverse Drain Current vs. Source to Drain Voltage



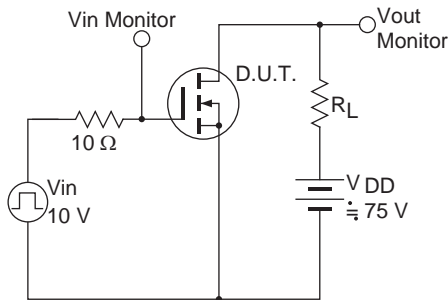
Gate to Source Cutoff Voltage vs. Case Temperature



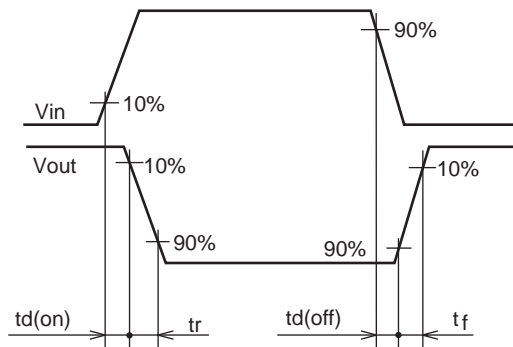
Normalized Transient Thermal Impedance vs. Pulse Width



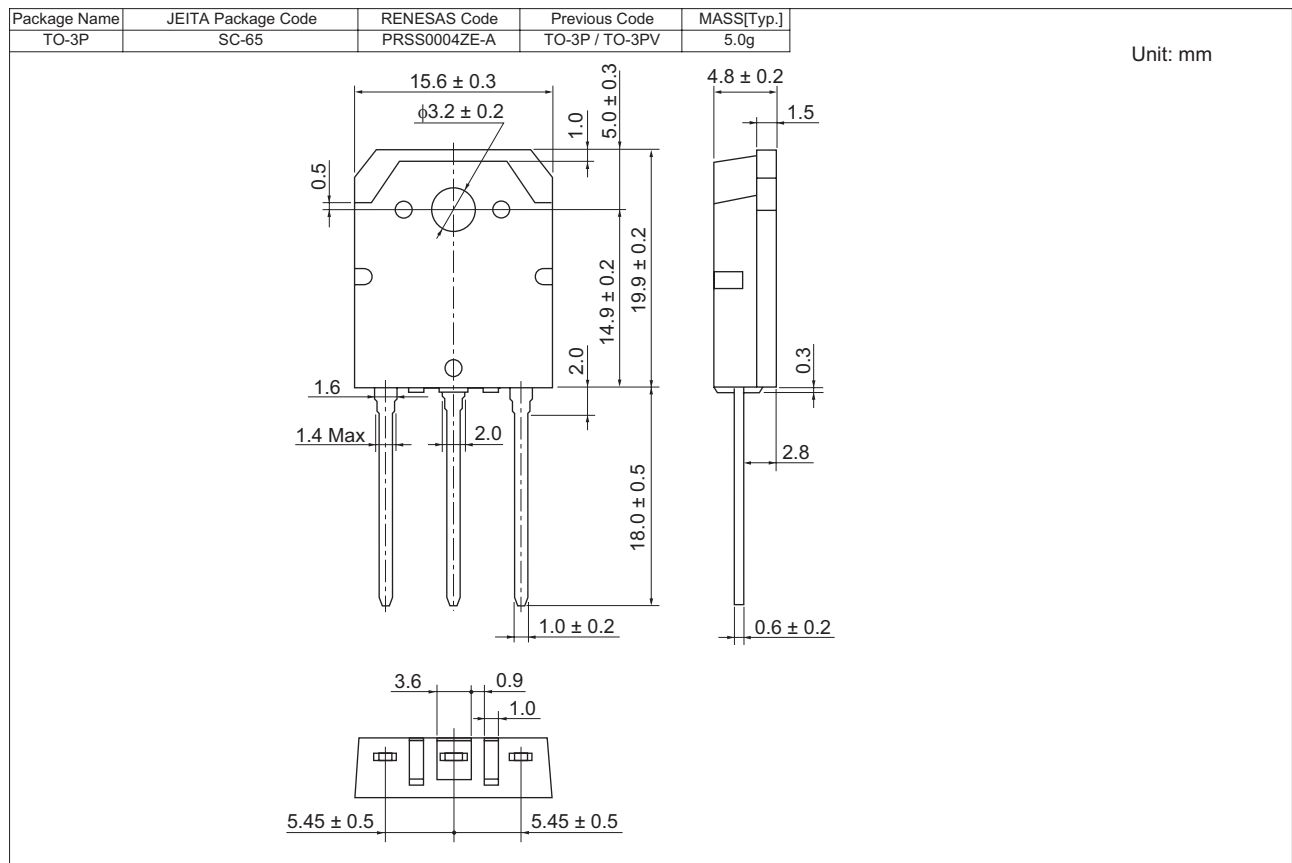
Switching Time Test Circuit



Waveform



Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
H5N1506P-E	360 pcs	Box (Tube)

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